

BLP25M710

Broadband LDMOS driver transistor

Rev. 1 — 29 August 2013

Product data sheet

1. Product profile

1.1 General description

A 10 W LDMOS power transistor for broadcast and industrial applications in the HF to 2500 MHz band.

Table 1. Application information

Test signal	f (MHz)	I _{DQ} (mA)	V _{DS} (V)	P _L (W)	G _p (dB)	η _D (%)	IMD _{shldr} (dBc)	PAR (dB)
DVB-T	858	110	28	1	20.9	17.1	-47.5 [1]	9.5 [2]
Pulsed RF [3]	2450	80	28	10	16.2	64.5	-	-

[1] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

[2] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

[3] Measured at $\delta = 10\%$, $t_p = 12\ \mu\text{s}$.

1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 2500 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

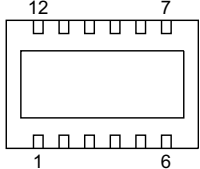
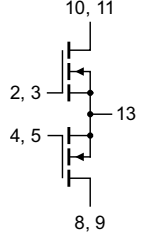
1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications



2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1, 6, 7, 12	n.c.	 <p>Transparent top view</p>	 <p>aaa-008925</p>
2, 3	gate1		
4, 5	gate2		
8, 9	drain2		
10, 11	drain1		
13	source		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BLP25M710	HVSON12	plastic thermal enhanced very thin small outline package; no leads; 12 terminals; body 6 × 4 × 0.85 mm	SOT1179-2

4. Limiting values

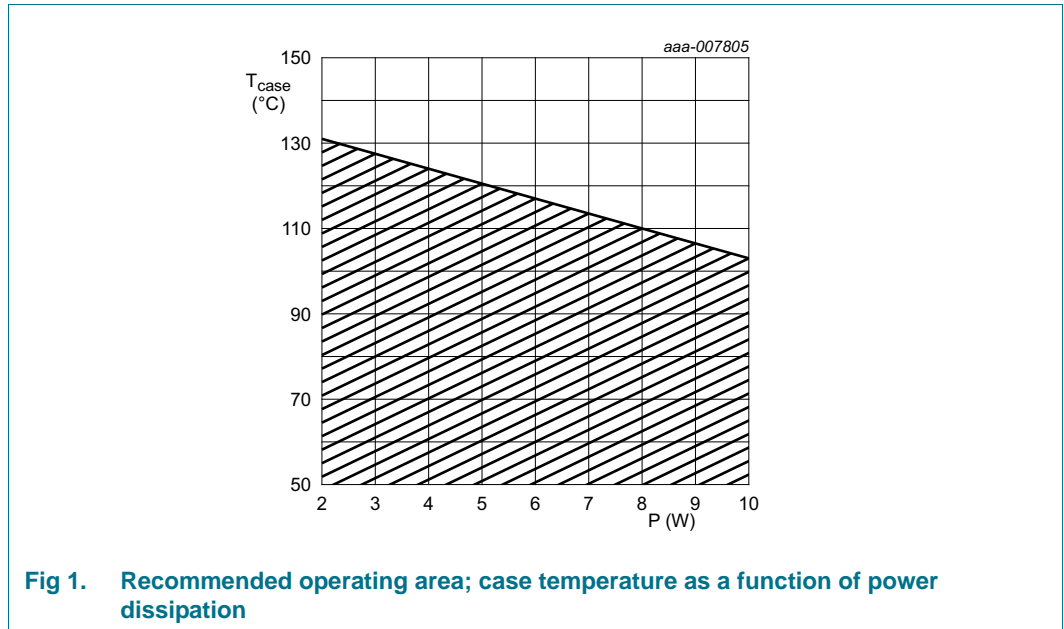
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	150	°C

5. Recommended operating conditions

See application note AN11198 for more details.



6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_{case} = 70\text{ °C}; P_L = 2\text{ W}$	3.2	K/W

7. Characteristics

Table 6. DC characteristics

$T_j = 25\text{ °C};$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 0.18\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 18\text{ mA}$	1.5	1.9	2.3	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 28\text{ V}$	-1.4	-	+1.4	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$	-	3.2	-	A
I_{GSS}	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	140	nA
g_{fs}	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 18\text{ mA}$	-	160	-	mS
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}; I_D = 630\text{ mA}$	-	1000	-	$\text{m}\Omega$

Table 7. RF characteristics

Test signal: 1-tone pulsed; $t_p = 50 \mu\text{s}$; $\delta = 10\%$; $f = 2140 \text{ MHz}$; RF performance at $V_{DS} = 28 \text{ V}$; $I_{DQ} = 110 \text{ mA}$; $T_{case} = 25 \text{ }^\circ\text{C}$; unless otherwise specified, in a production circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$P_{L(AV)} = 2 \text{ W}$	15	16	-	dB
η_D	drain efficiency	$P_{L(AV)} = 2 \text{ W}$	20	23	-	%
$P_{L(1dB)}$	output power at 1 dB gain compression		11	-	-	W
RL_{in}	input return loss	$P_{L(AV)} = 2 \text{ W}$	-	-16	-12	dB

8. Test information

8.1 Ruggedness in class-AB operation

The BLP25M710 is capable of withstanding a load mismatch corresponding to $VSWR = 10 : 1$ through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{DQ} = 110 \text{ mA}$; $P_L = 10 \text{ W (CW)}$.

9. Package outline

HVSON12: plastic thermal enhanced very thin small outline package; no leads;
12 terminals; body 4 x 6 x 0.85 mm

SOT1179-2

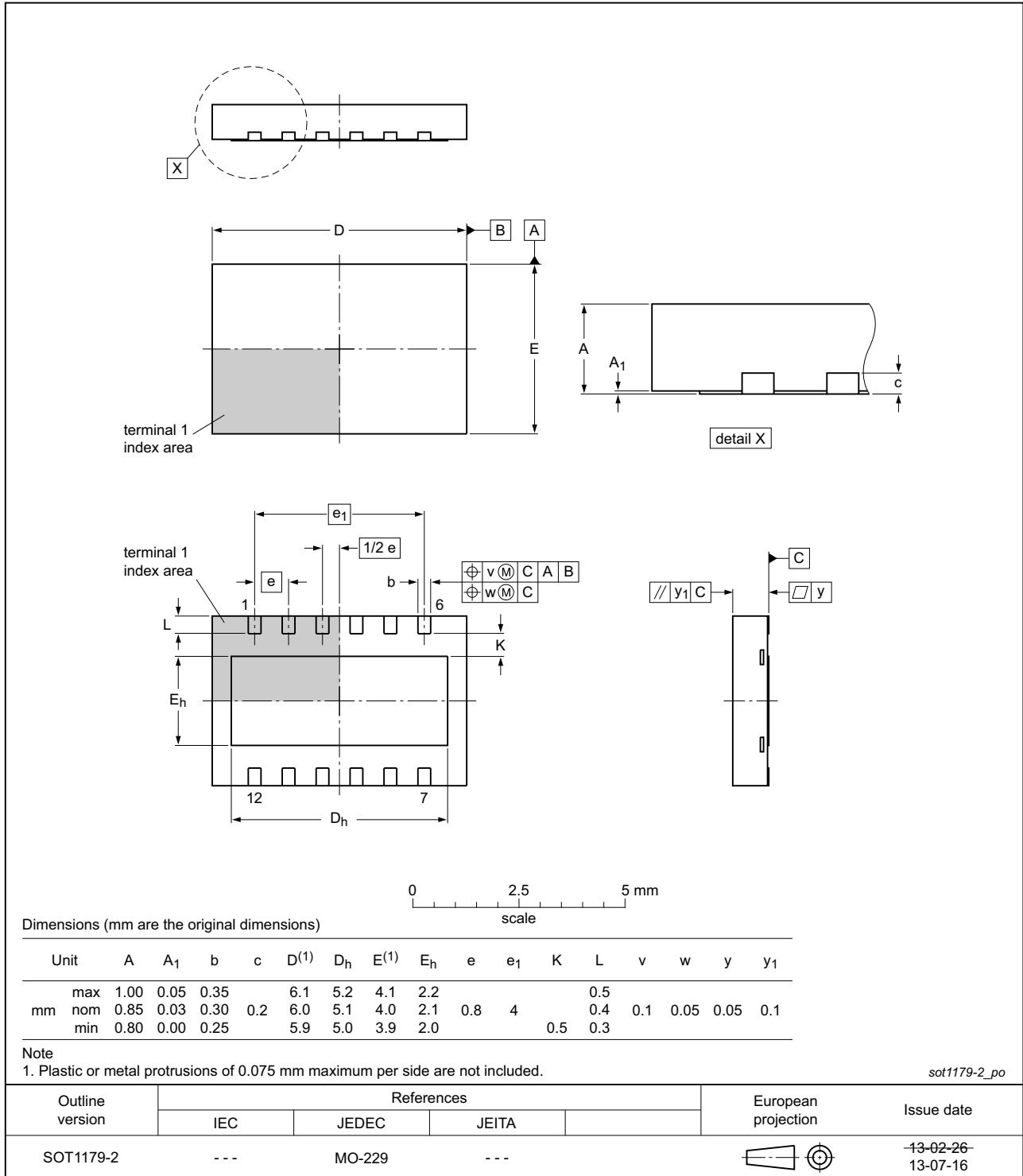


Fig 2. Package outline SOT1179-2 (HVSON12)

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

11. Abbreviations

Table 8. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DVB-T	Digital Video Broadcast - Terrestrial
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
PAR	Peak-to-Average Ratio
VSWR	Voltage Standing-Wave Ratio

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLP25M710 v.1	20130829	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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